

SSC8L32GN6

N-Channel Enhancement Mode MOSFET

> Features

VDS	VGS	RDSON Typ.	ID
30V	±20V	2.7mR@10V	mR@10V 95A
	±20V	3.7mR@4V5	95A

Description

This device uses advanced trench technology to provide excellent RDSON and low gate charge. This device is suitable for use as a load switch or in PWM applications.

Applications

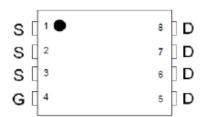
- Load Switch
- Portable Devices
- DCDC conversion

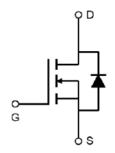
Ordering Information

Device	Package	Shipping
SSC8L32GN6	PDFN5x6	5000/Reel

Pin configuration

Top view







Bottom View



(XX: year/YY: week)

Marking



➤ Absolute Maximum Ratings(T_A=25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
V_{DSS}	Drain-to-Source Voltage	30	V
V_{GSS}	Gate-to-Source Voltage	±20	V
I _D	Continuous Drain Current ^a	95	Α
I _{DM}	Pulsed Drain Current ^b	140	Α
P_D	Power Dissipation ^c	70	W
P _{DSM}	Power Dissipation ^a	5.25	W
TJ	Operation junction temperature	-55 to 150	°C
T _{STG}	Storage temperature range	-55 to 150	°C

➤ Thermal Resistance Ratings(T_A=25°C unless otherwise noted)

Symbol	Parameter	Typical	Maximum	Unit
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance ^a		39	°C/W
ReJC	Junction-to-Case Thermal Resistance		6.5	C/VV

Note:

- a. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in² FR-4 board with 2oz.copper,in a still air environment with T_A =25°C. The value in any given application depends on the user is specific board design. The current rating is based on the t \leq 10s thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation P_D is based on $T_{J(MAX)}$ =150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

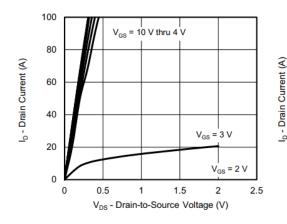


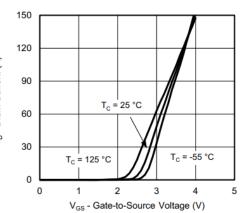
ightharpoonup **Electronics Characteristics**(T_A=25 $^{\circ}$ C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур.	Max	Unit
V(BR)DSS	Drain-Source Breakdown Voltage	VGS=0V,ID=250uA	30			V
VGS (th)	Gate Threshold Voltage	VDS=VGS,ID=250uA	1	1.5	2.2	V
DD0()	Drain-Source On-	VGS=10V,ID=20A		2.7	3	mR
RDS(on)	Resistance	VGS=4.5V,ID=10A		3.7	4.5	
IDSS	Zero Gate Voltage Drain Current	VDS=30V,VGS=0V			1	uA
IGSS	Gate-Source leak	VGS=±20V,VDS=0V			±100	nA
VSD	Forward Voltage	VGS=0V,IS=1A			1.3	V
Ciss	Input Capacitance			2550		
Coss	Output Capacitance	VDS=20V, VGS=0V, f=1MHZ		550		pF
Crss	Reverse Transfer Capacitance			110		
Qg	Total Gate Charge			29.5		
Qgs	Gate to source charge	VDS=15V , ID=20A , VGS=4.5V		6		nC
Qgd	Gate to drain charge			5.5		
TD(ON)	Turn-on delay time	VGEN=10V, VDS=15V, RL=15R,		10		ns
TD(OFF)	Turn-off delay time	RG=3R,ID=1A		25		



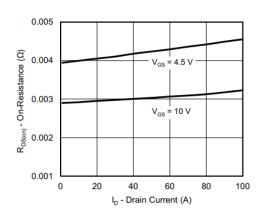
➤ Typical Characteristics(T_A=25°C unless otherwise noted)

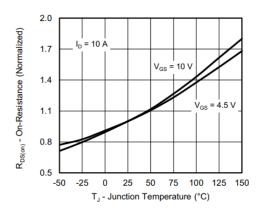




Output Characteristics

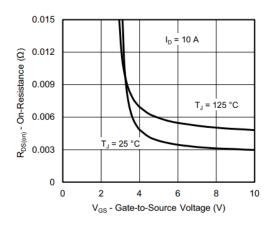
Transfer Characteristics

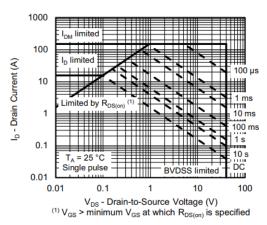




On-Resistance vs. Drain Current and Gate Voltage

On-Resistance vs. Junction Temperature



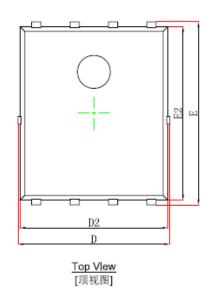


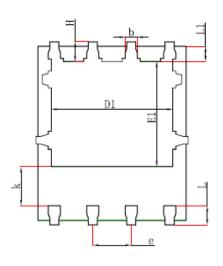
On-Resistance vs. Gate-to-Source Voltage

Safe Operating Area, Junction-to-Ambient

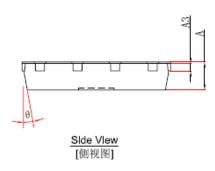


> Package Information





Bottom Vlew [背视图]



Package: DNF5X6-8L

Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	0.900	1.000	0.035	0.039	
A3	0.254	4REF	0.010	0.010REF	
D	4.944	5.096	0.195	0.201	
E	5.974	6.126	0.235	0.241	
D1	3.910	4.110	0.154	0.162	
E1	3.375	3.575	0.133	0.141	
D2	4.824	4.976	0.190	0.196	
E2	5.674	5.826	0.223	0.229	
k	1.190	1.390	0.047	0.055	
b	0.350	0.450	0.014	0.018	
e	1.270	OTYP	0.050	TYP	
L	0.559	0.711	0.022	0.028	
L1	0.424	0.576	0.017	0.023	
Н	0.574	0.726	0.023	0.029	
θ	10°	12°	10°	12°	



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